

Bias Resistor Transistor

PNP Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

LDTA143XLT1G

- Applications

Inverter, Interface, Driver

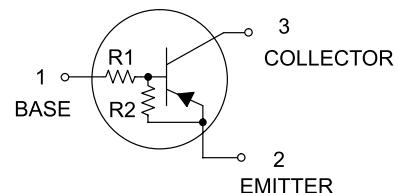
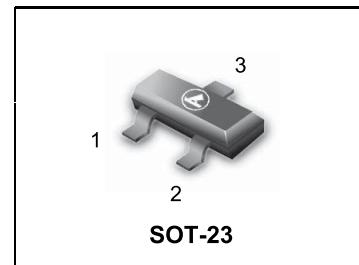
- Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making the device design easy.

- We declare that the material of product compliance with RoHS requirements.

- Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits		Unit
Supply voltage	Vcc	-50		V
Input voltage	Vi	-20 to +7		V
Output current	Io	-100		mA
	Ic(Max.)	-100		
Power dissipation	Pd	200		mW
Junction temperature	Tj	150		°C
Storage temperature	Tstg	-55 to +150		°C



DEVICE MARKING AND RESISTOR VALUES

Device	Marking	R1 (K)	R2 (K)	Shipping
LDTA143XLT1G	L3	4.7	10	3000/Tape & Reel
LDTA143XLT3G	L3	4.7	10	10000/Tape & Reel

- Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V _{i(off)}	—	—	-0.3	V	V _{cc} =-5V, I _o =-100μA
	V _{i(on)}	-2.5	—	—		V _o =-0.3V, I _o =-20mA
Output voltage	V _{o(on)}	—	-0.1	-0.3	V	I _o /I _e =-10mA/-0.5mA
Input current	I _i	—	—	-1.8	mA	V _i =-5V
Output current	I _{o(off)}	—	—	-0.5	μA	V _{cc} =-50V, V _i =0V
DC current gain	G _i	30	—	—	—	V _o =-5V, I _o =-10mA
Input resistance	R _i	3.29	4.7	6.11	kΩ	—
Resistance ratio	R ₂ /R ₁	1.7	2.1	2.6	—	—
Transition frequency	f _T *	—	250	—	MHz	V _{CE} =-10V, I _e =5mA, f=100MHz

* Characteristics of built-in transistor

LDTA143XLT1G

●Electrical characteristic curves

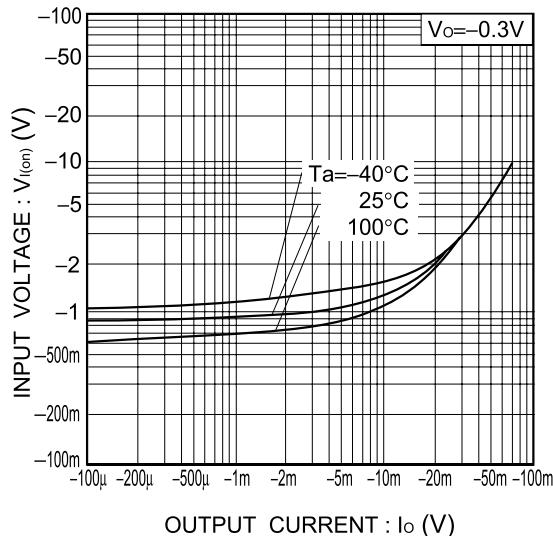


Fig.1 Input voltage vs. output current
(ON characteristics)

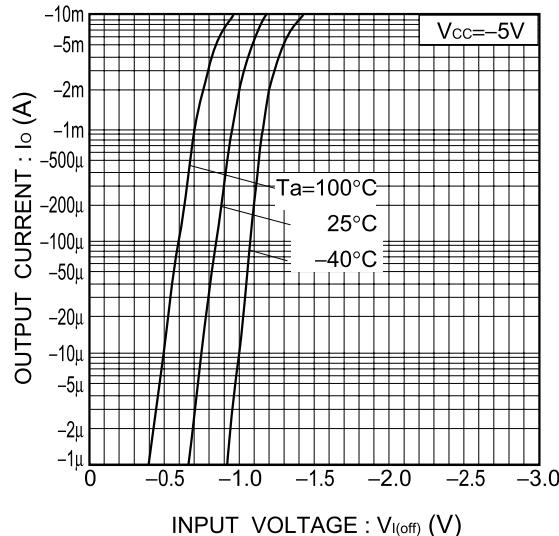


Fig.2 Output current vs. input voltage
(OFF characteristics)

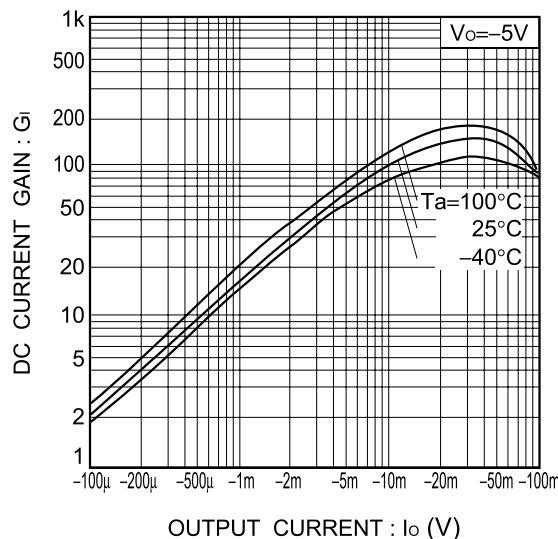


Fig.3 DC current gain vs. output current

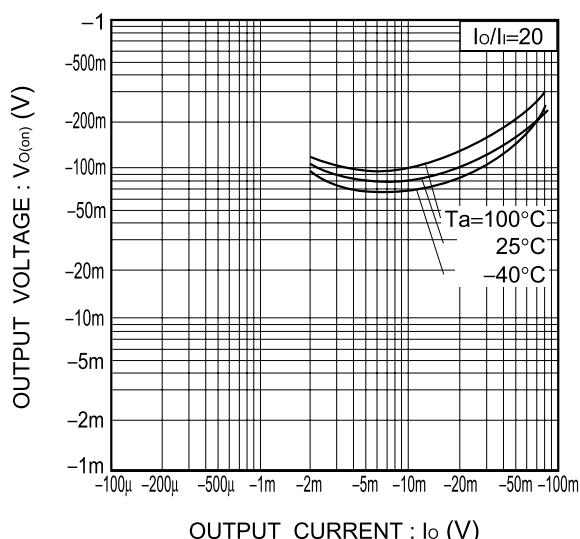
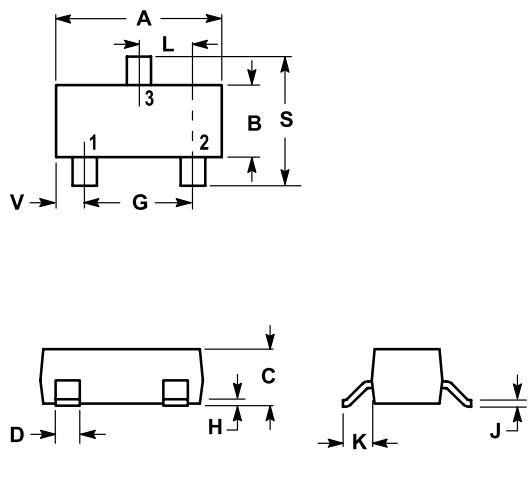


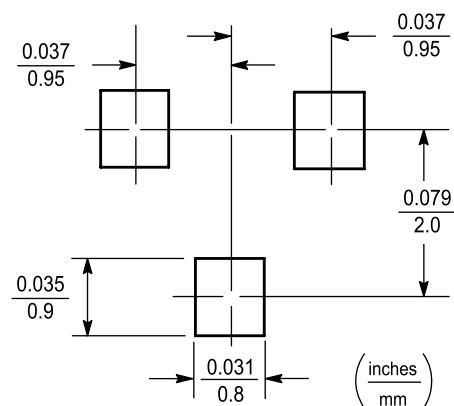
Fig.4 Output voltage vs. output current

LDTA143XLT1G
SOT-23
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60



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